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ARTICLE

Tuning of Fluorine Content in Graphene: Towards Large Scale Production of Stoichiometric Fluorographene

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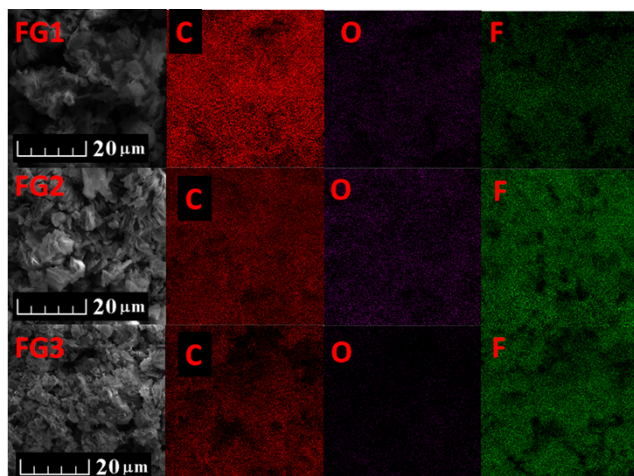
SUPPORTNIG INFORMATION

Fig. SI1 The distribution of elements in fluorinated graphenes obtained by EDS.

Table SI 1 The deconvolution results of C 1s peak.

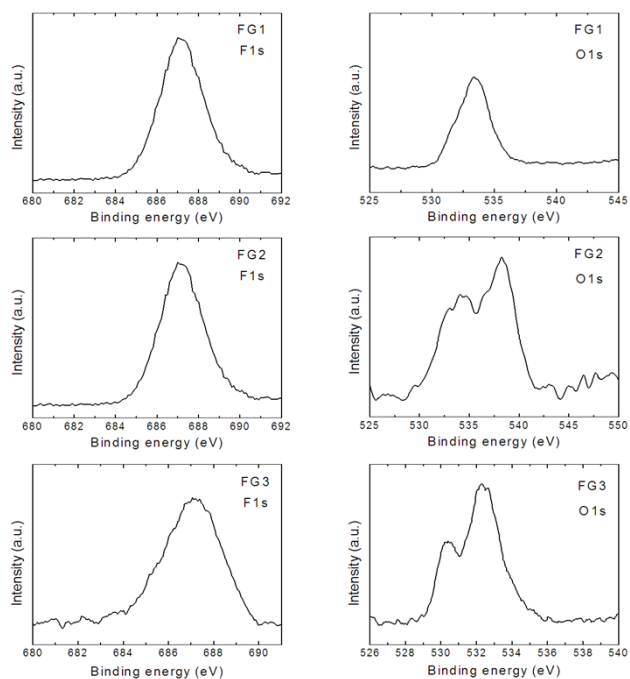| Bond type	FG1	FG2	FG3
C=C	48.0	56.4	37.7
C-C	24.9	5.8	20.8
C-O	11.5	11.6	7.2
C=O	5.9	6.3	7.2
C-F	2.9	5.5	5.5
O-C=O	2.8	5.5	0.1
$\pi - \pi^*$	2.8	0.0	3.6
CF_2	1.3	4.7	6.0
CF_3	0.0	4.1	11.9

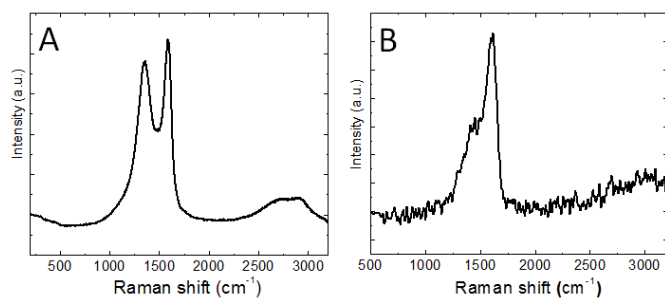**Fig. SI2** High resolution spectra of O 1s and F 1s peak in fluorinated graphenes.

Fig. SI3 The Raman spectra of graphene used for fluorination measured using 532 nm laser (Fig. SI3-A) and 325 nm laser (Fig. SI3-B).
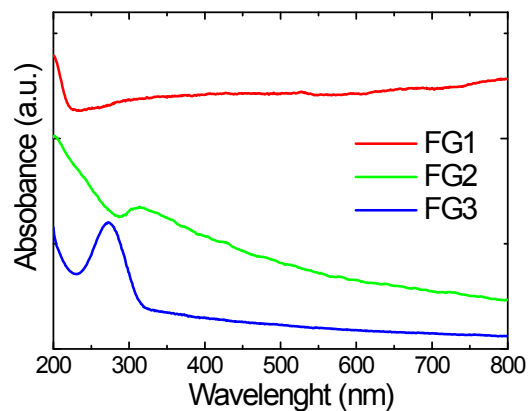

Fig. SI4 The UV-VIS spectra of fluorographene suspension in acetonitrile (1 mg/ml).

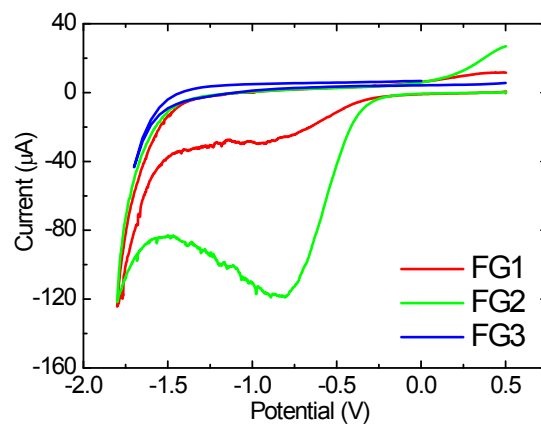**Fig. SI5** The inherent electrochemistry of fluorinated graphenes. Measurement was performed in PBS supporting electrolyte (pH = 7.0, c = 0.05 M).
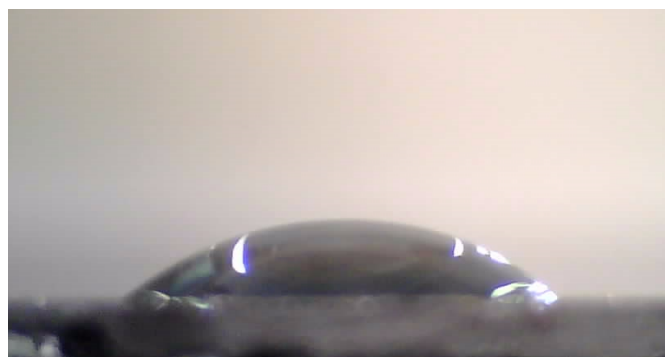

Fig. SI6 The contact angle of silicon wafer coated using graphene before fluorination procedure.